

The RF Line  
**NPN Silicon**  
**RF Power Transistor**

... designed primarily for wideband large-signal output amplifier stages in the 100 to 500 MHz frequency range.

- Guaranteed Performance @ 400 MHz, 28 Vdc  
Output Power = 80 Watts over 225 to 400 MHz Band  
Minimum Gain = 7.3 dB @ 400 MHz
- Built-In Matching Network for Broadband Operation Using Double Match Technique
- 100% Tested for Load Mismatch at all Phase Angles with 30:1 VSWR
- Gold Metallization System for High Reliability Applications
- Characterized for 100 to 500 MHz

**MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	33	Vdc
Collector-Base Voltage	$V_{CBO}$	60	Vdc
Emitter-Base Voltage	$V_{EBO}$	4.0	Vdc
Collector Current — Continuous	$I_C$	9.0	Adc
— Peak		12	
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ (1)	$P_D$	250	Watts
Derate above $25^\circ\text{C}$		1.43	W/ $^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-65 to +150	$^\circ\text{C}$

**THERMAL CHARACTERISTICS**

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.7	$^\circ\text{C/W}$

**ELECTRICAL CHARACTERISTICS** ( $T_C = 25^\circ\text{C}$  unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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**OFF CHARACTERISTICS**

Collector-Emitter Breakdown Voltage ( $I_C = 80\text{ mAdc}$ , $I_B = 0$ )	$V_{(BR)CEO}$	33	—	—	Vdc
Collector-Emitter Breakdown Voltage ( $I_C = 80\text{ mAdc}$ , $V_{BE} = 0$ )	$V_{(BR)CES}$	60	—	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 8.0\text{ mAdc}$ , $I_C = 0$ )	$V_{(BR)EBO}$	4.0	—	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = 80\text{ mAdc}$ , $I_C = 0$ )	$V_{(BR)CBO}$	60	—	—	Vdc
Collector Cutoff Current ( $V_{CB} = 30\text{ Vdc}$ , $I_E = 0$ )	$I_{CBO}$	—	—	5.0	mAdc

**ON CHARACTERISTICS**

DC Current Gain ( $I_C = 4.0\text{ Adc}$ , $V_{CE} = 5.0\text{ Vdc}$ )	$h_{FE}$	20	—	80	—
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**DYNAMIC CHARACTERISTICS**

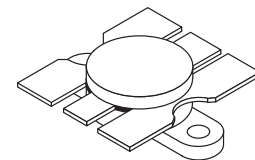
Output Capacitance ( $V_{CB} = 28\text{ Vdc}$ , $I_E = 0$ , $f = 1.0\text{ MHz}$ )	$C_{ob}$	—	95	125	pF
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NOTE:

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

**MRF327**

**80 W, 100 to 500 MHz**  
**CONTROLLED "Q"**  
**BROADBAND RF POWER**  
**TRANSISTOR**  
**NPN SILICON**



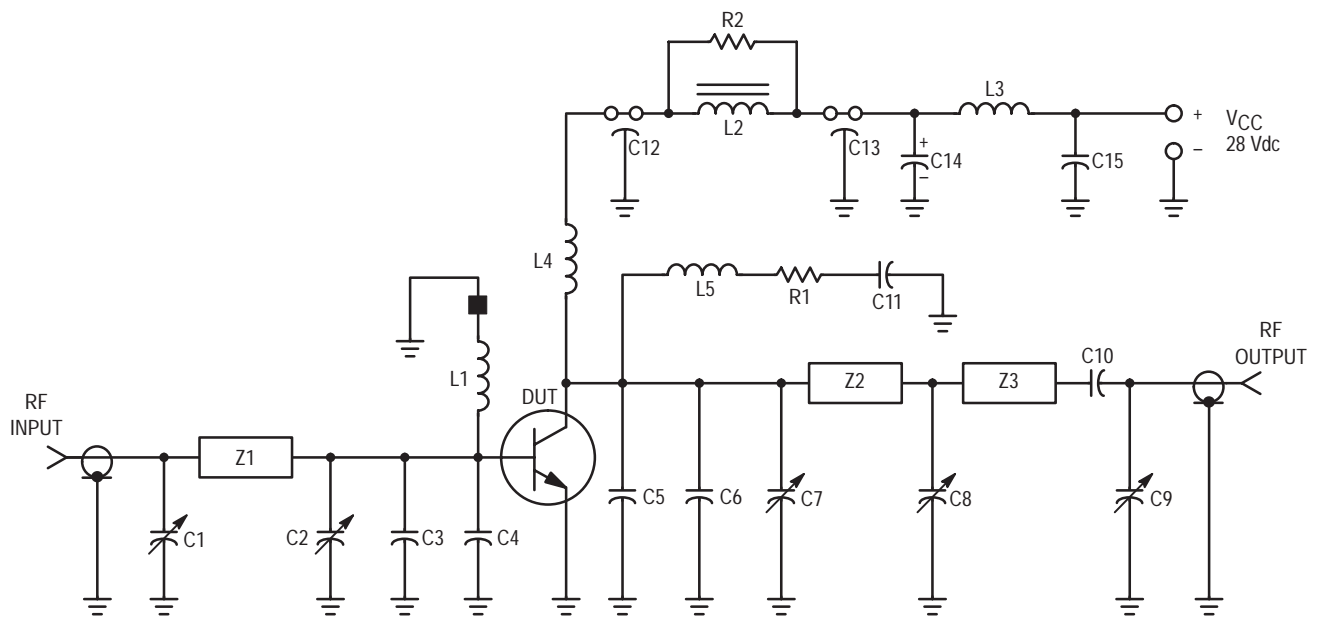
**CASE 316-01, STYLE 1**

NOT RECOMMENDED FOR NEW DESIGN

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**ELECTRICAL CHARACTERISTICS – continued** ( $T_C = 25^\circ\text{C}$  unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>FUNCTIONAL TESTS</b> (Figure 1)					
Common-Emitter Amplifier Power Gain ( $V_{CC} = 28\text{ Vdc}$ , $P_{Out} = 80\text{ W}$ , $f = 400\text{ MHz}$ )	$G_{PE}$	7.3	9.0	—	dB
Collector Efficiency ( $V_{CC} = 28\text{ Vdc}$ , $P_{Out} = 80\text{ W}$ , $f = 400\text{ MHz}$ )	$\eta$	50	60	—	%
Load Mismatch ( $V_{CC} = 28\text{ Vdc}$ , $P_{Out} = 80\text{ W}$ , $f = 400\text{ MHz}$ , $VSWR = 30:1$ All Phase Angles)	$\psi$	No Degradation in Output Power			



C1, C2, C7, C8, C9 — 1.0–20 pF Piston Trimmer (Johanson JMC 5501)

C3, C4 — 36 pF ATC 100 mil Chip Capacitor

C5, C6 — 43 pF ATC 100 mil Chip Capacitor

C10 — 100 pF UNELCO

C11, C15 — 0.1  $\mu\text{F}$  Erie Redcap

C12, C13 — 680 pF Feedthru

C14 — 1.0  $\mu\text{F}$  50 V Tantalum

L1 — 4 Turns #22 AWG Enameled, 3/16" ID Closewound with Ferroxcube Bead (#56–590–65/4B) on Ground End of Coil

L2 — Ferroxcube VK200–19/4B Ferrite Choke

L3 — 7 Turns #18 AWG, 11/16" Long, Wound on a 100 k $\Omega$  2.0 Watt

L4 — 6 Turns #20 AWG Enameled, 3/16" ID Closewound

L5 — 4 Turns #22 AWG Enameled, 1/8" ID Closewound

Z1 — Microstrip 0.2" W x 1.5" L

Z2 — Microstrip 0.17" W x 1.16" L

Z3 — Microstrip 0.17" W x 0.63" L

R1, R2 — 10  $\Omega$  2.0 Watt

Board — Glass Teflon  $\epsilon_r = 2.56$ ,  $t = 0.062"$

Input/Output Connectors Type N

DUT Socket Lead Frame Etched from 80–mil–Thick Copper

**Figure 1. 400 MHz Test Circuit**

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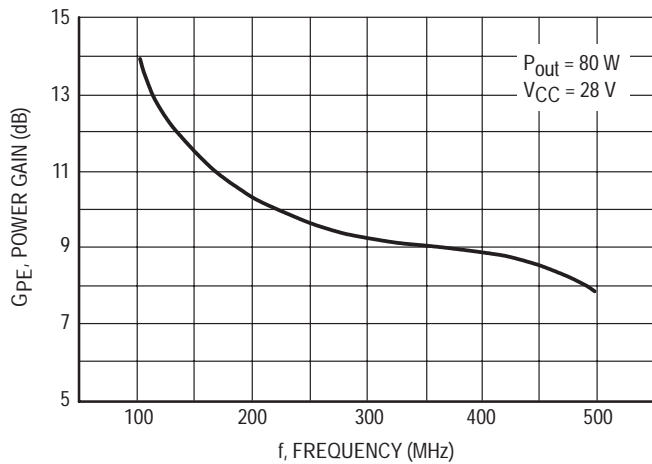


Figure 2. Power Gain versus Frequency

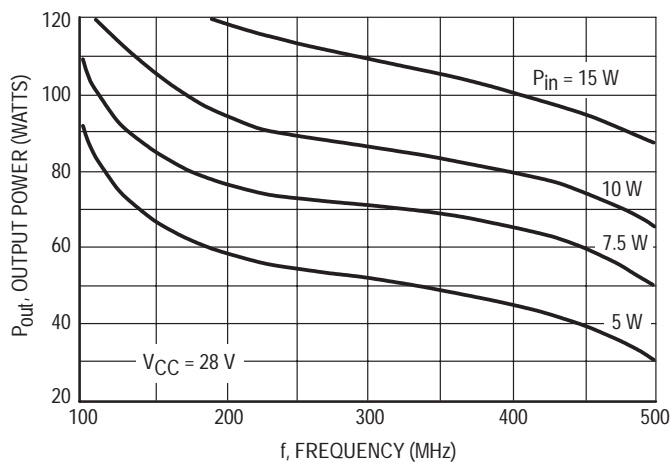


Figure 3. Output Power versus Frequency

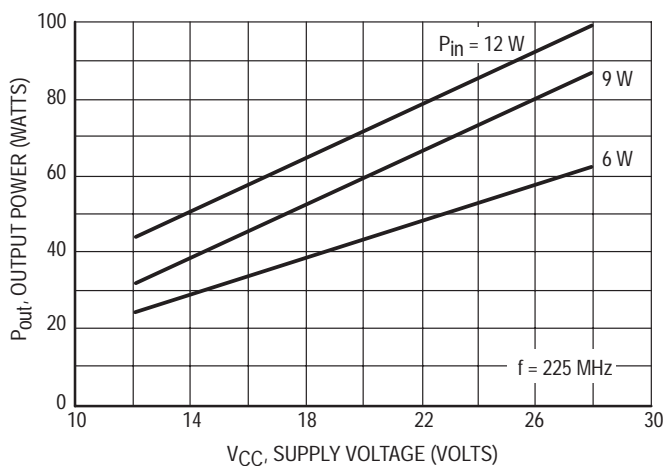


Figure 4. Output Power versus Supply Voltage

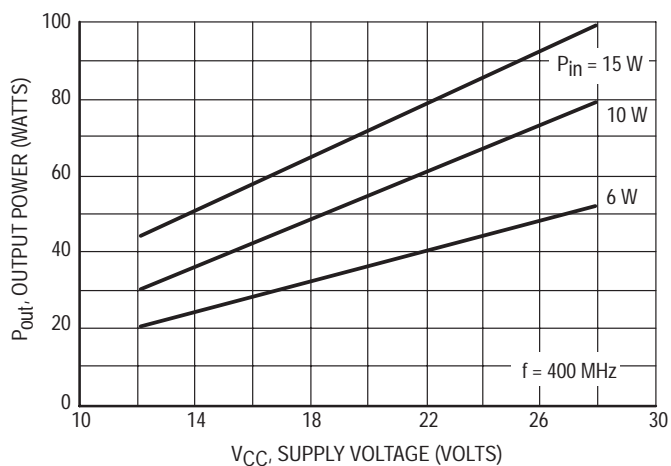


Figure 5. Output Power versus Supply Voltage

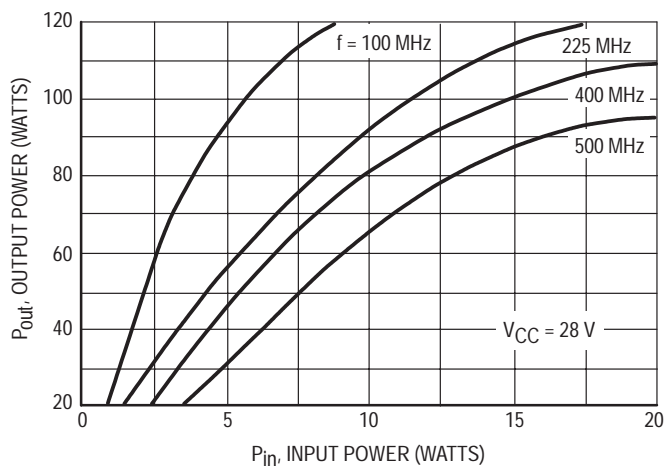


Figure 6. Output Power versus Input Power

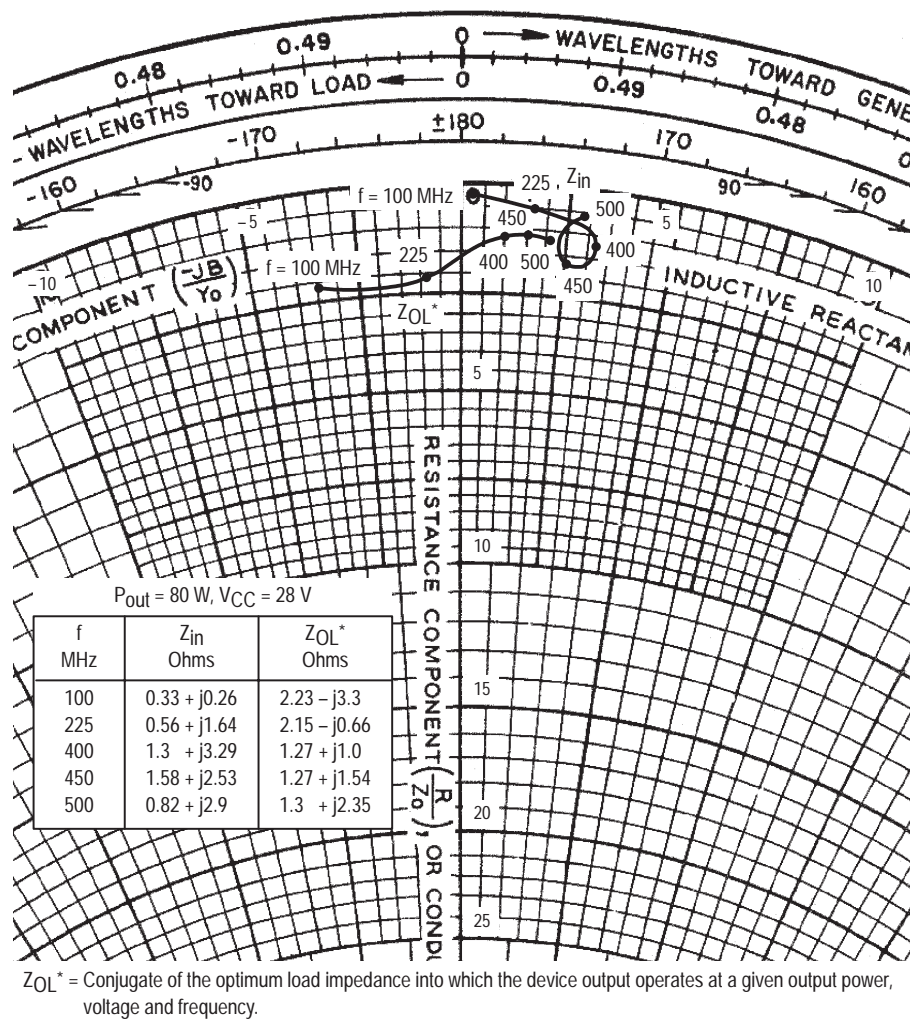
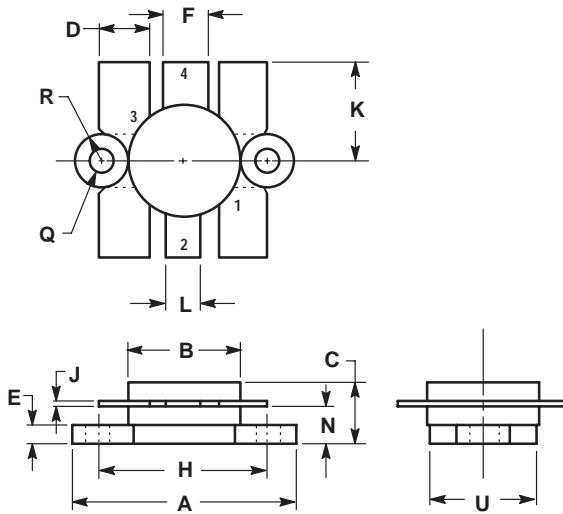


Figure 7. Series Equivalent Input-Output Impedance

# PACKAGE DIMENSIONS

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NOTES:  
1. FLANGE IS ISOLATED IN ALL STYLES.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	24.38	25.14	0.960	0.990
B	12.45	12.95	0.490	0.510
C	5.97	7.62	0.235	0.300
D	5.33	5.58	0.210	0.220
E	2.16	3.04	0.085	0.120
F	5.08	5.33	0.200	0.210
H	18.29	18.54	0.720	0.730
J	0.10	0.15	0.004	0.006
K	10.29	11.17	0.405	0.440
L	3.81	4.06	0.150	0.160
N	3.81	4.31	0.150	0.170
Q	2.92	3.30	0.115	0.130
R	3.05	3.30	0.120	0.130
U	11.94	12.57	0.470	0.495

STYLE 1:  
PIN 1. EMITTER  
2. COLLECTOR  
3. EMITTER  
4. BASE

**CASE 316-01  
ISSUE D**

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**MRF327/D**

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